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Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[ON Semiconductor](#)
[MJ14002G](#)

For any questions, you can email us directly:

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MJ14001 (PNP), MJ14002* (NPN), MJ14003* (PNP)

*Preferred Devices

High-Current Complementary Silicon Power Transistors

Designed for use in high-power amplifier and switching circuit applications.

Features

- High Current Capability – I_C Continuous = 60 Amperes
- DC Current Gain – $h_{FE} = 15-100$ @ $I_C = 50$ Adc
- Low Collector–Emitter Saturation Voltage – $V_{CE(sat)} = 2.5$ Vdc (Max) @ $I_C = 50$ Adc
- Pb–Free Packages are Available*

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	60 80	Vdc
Collector–Base Voltage	V_{CBO}	60 80	Vdc
Emitter–Base Voltage	V_{EBO}	5.0	Vdc
Collector Current – Continuous	I_C	60	Adc
Base Current – Continuous	I_B	15	Adc
Emitter Current – Continuous	I_E	75	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate Above 25°C	P_D	300 1.71	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

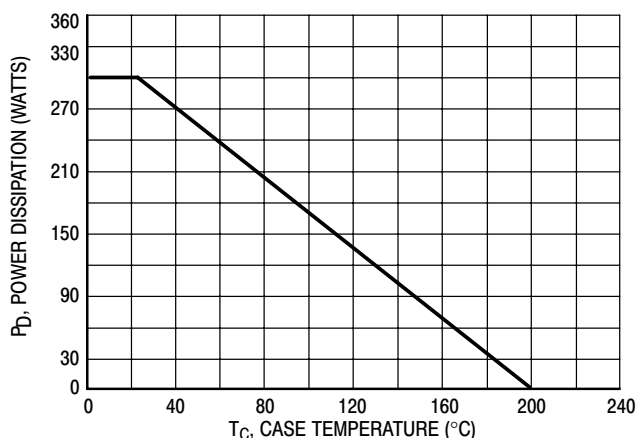


Figure 1. Power Derating

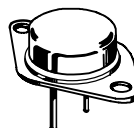


ON Semiconductor®

<http://onsemi.com>

60 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60–80 VOLTS, 300 WATTS

MARKING DIAGRAM



TO-204 (TO-3)
CASE 197A
STYLE 1

- MJ1400x = Device Code
xx = 1, 2, or 3
- G = Pb–Free Package
- A = Location Code
- YY = Year
- WW = Work Week
- MEX = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
MJ14001	TO-3	100 Units/Tray
MJ14001G	TO-3 (Pb–Free)	100 Units/Tray
MJ14002	TO-3	100 Units/Tray
MJ14002G	TO-3 (Pb–Free)	100 Units/Tray
MJ14003	TO-3	100 Units/Tray
MJ14003G	TO-3 (Pb–Free)	100 Units/Tray

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MJ14001 (PNP), MJ14002* (NPN), MJ14003* (PNP)

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.584	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage (Note 1) ($I_C = 200$ mA, $I_B = 0$)	MJ14001 MJ14002, MJ14003	$V_{CEO(sus)}$	60 80	- -	Vdc
Collector Cutoff Current ($V_{CE} = 30$ Vdc, $I_B = 0$) ($V_{CE} = 40$ Vdc, $I_B = 0$)	MJ14001 MJ14002, MJ14003	I_{CEO}	- -	1.0 1.0	mA
Collector Cutoff Current ($V_{CE} = 60$ Vdc, $V_{BE(off)} = 1.5$ V) ($V_{CE} = 80$ Vdc, $V_{BE(off)} = 1.5$ V)	MJ14001 MJ14002, MJ14003	I_{CEX}	- -	1.0 1.0	mA
Collector Cutoff Current ($V_{CB} = 60$ Vdc, $I_E = 0$) ($V_{CB} = 80$ Vdc, $I_E = 0$)	MJ14001 MJ14002, MJ14003	I_{CBO}	- -	1.0 1.0	mA
Emitter Cutoff Current ($V_{BE} = 5.0$ Vdc, $I_C = 0$)		I_{EBO}	-	1.0	mA

ON CHARACTERISTICS

DC Current Gain (Note 1) ($I_C = 25$ Adc, $V_{CE} = 3.0$ V) ($I_C = 50$ Adc, $V_{CE} = 3.0$ V) ($I_C = 60$ Adc, $V_{CE} = 3.0$ V)		h_{FE}	30 15 5.0	- 100 -	-
Collector-Emitter Saturation Voltage (Note 1) ($I_C = 25$ Adc, $I_B = 2.5$ Adc) ($I_C = 50$ Adc, $I_B = 5.0$ Adc) ($I_C = 60$ Adc, $I_B = 12$ Adc)		$V_{CE(sat)}$	- - -	1.0 2.5 3.0	Vdc
Base-Emitter Saturation Voltage (Note 1) ($I_C = 25$ Adc, $I_B = 2.5$ Adc) ($I_C = 50$ Adc, $I_B = 5.0$ Adc) ($I_C = 60$ Adc, $I_B = 12$ Adc)		$V_{BE(sat)}$	- - -	2.0 3.0 4.0	Vdc

DYNAMIC CHARACTERISTICS

Output Capacitance ($V_{CB} = 10$ Vdc, $I_E = 0$, $f = 0.1$ MHz)		C_{ob}	-	2000	pF
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1. Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2.0\%$.

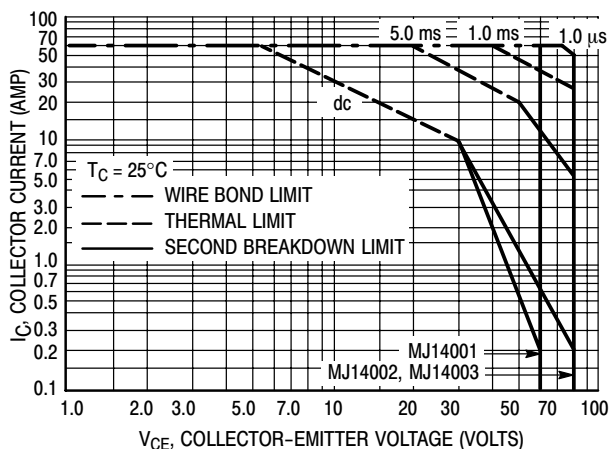


Figure 2. Maximum Rated Forward Biased Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation: i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_{J(pk)} = 200^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 200^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

MJ14001 (PNP), MJ14002* (NPN), MJ14003* (PNP)

TYPICAL ELECTRICAL CHARACTERISTICS

MJ14002 (NPN)

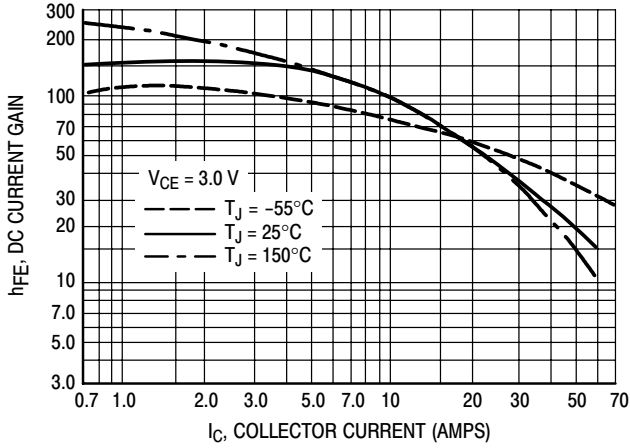


Figure 3. DC Current Gain

MJ14001, MJ14003 (PNP)

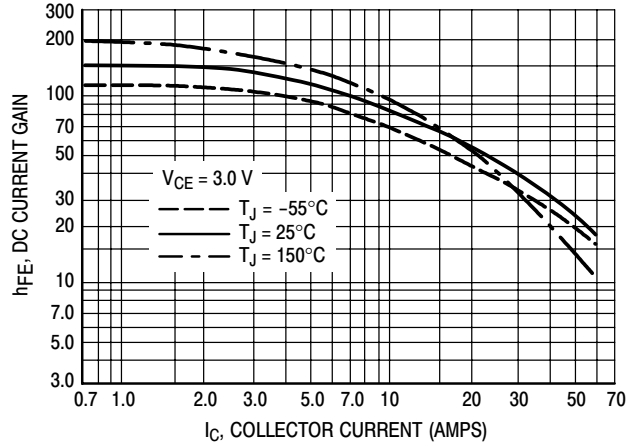


Figure 4. DC Current Gain

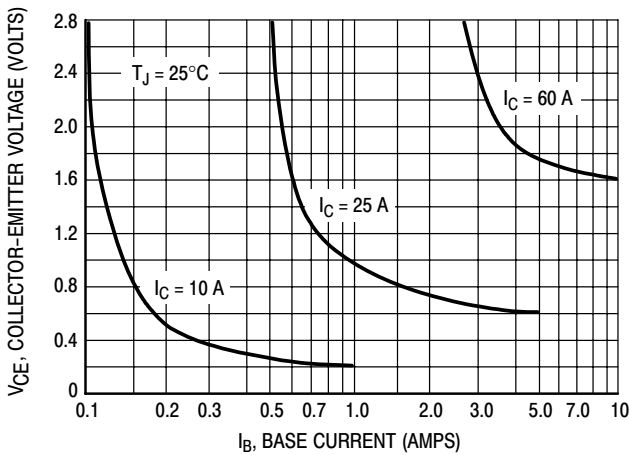


Figure 5. Collector Saturation Region

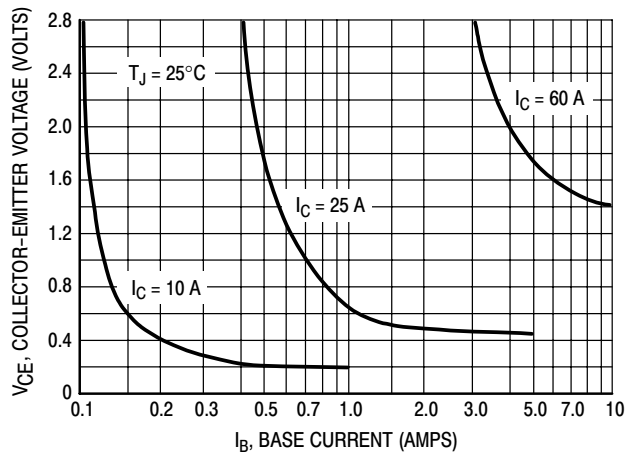


Figure 6. Collector Saturation Region

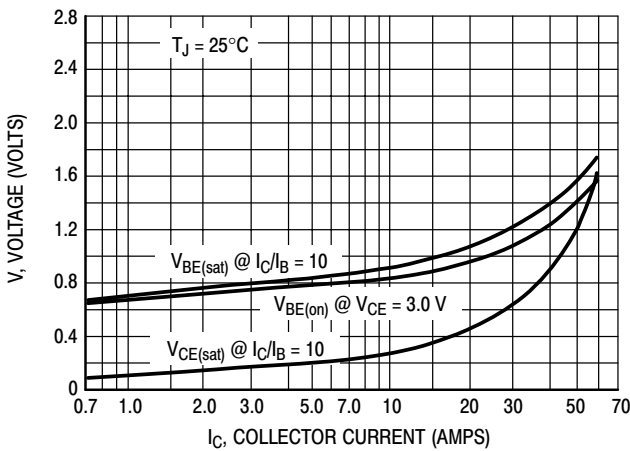


Figure 7. "On" Voltages

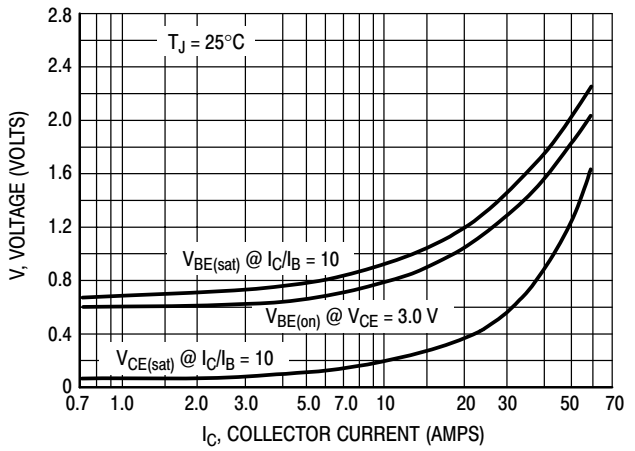


Figure 8. "On" Voltages

MJ14001 (PNP), MJ14002* (NPN), MJ14003* (PNP)

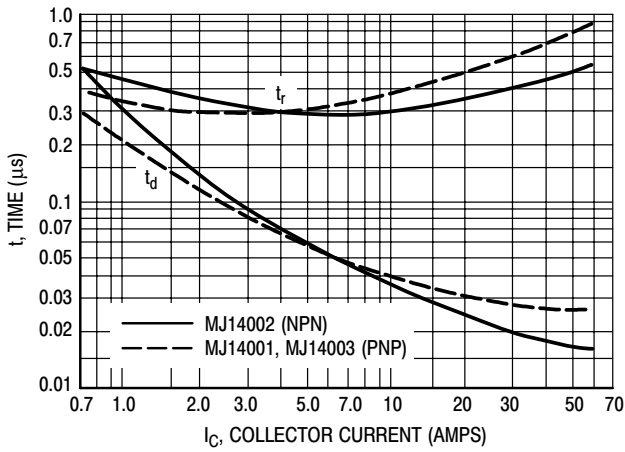


Figure 9. Turn-On Switching Times

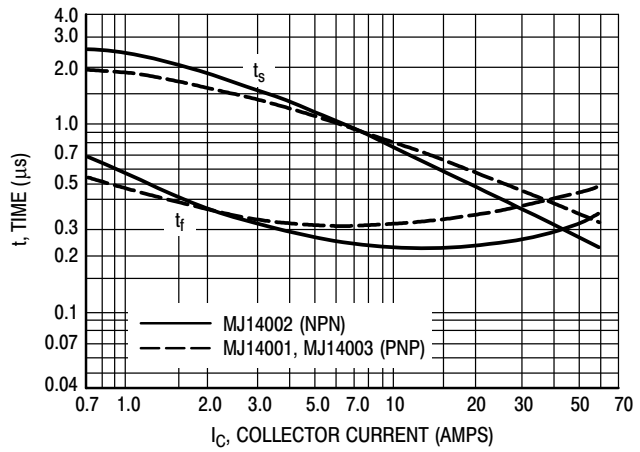


Figure 10. Turn-Off Switching Times

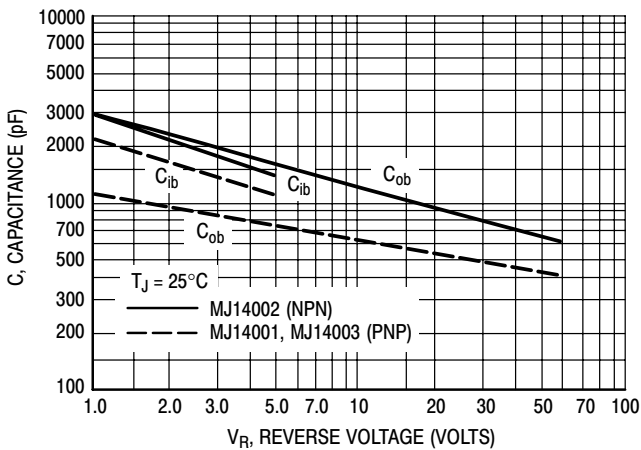
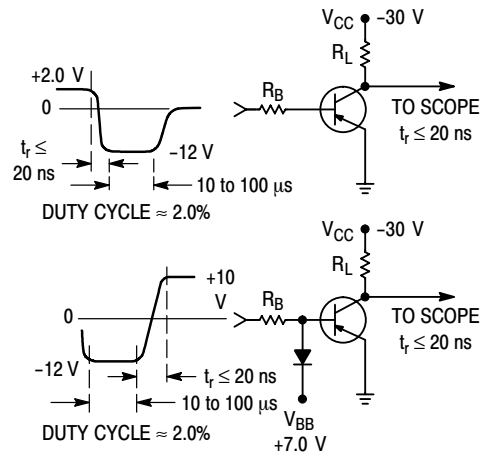


Figure 11. Capacitance Variation



FOR CURVES OF FIGURES 3 & 6, R_B & R_L ARE VARIED. INPUT LEVELS ARE APPROXIMATELY AS SHOWN. FOR NPN CIRCUITS, REVERSE ALL POLARITIES.

Figure 12. Switching Test Circuit

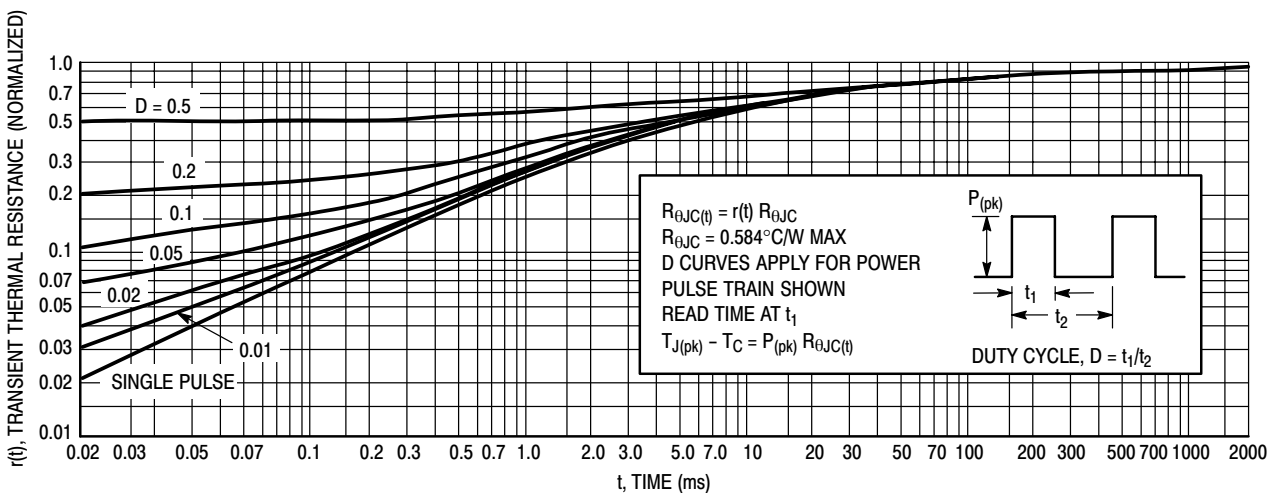
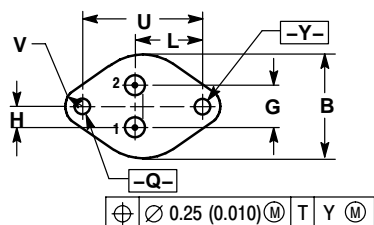
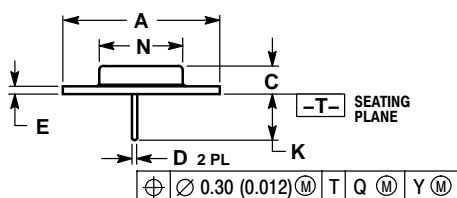


Figure 13. Thermal Response

MJ14001 (PNP), MJ14002* (NPN), MJ14003* (PNP)

PACKAGE DIMENSIONS

TO-204 (TO-3)
CASE 197A-05
ISSUE K




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.530 REF		38.86	REF
B	0.990	1.050	25.15	26.67
C	0.250	0.335	6.35	8.51
D	0.057	0.063	1.45	1.60
E	0.060	0.070	1.53	1.77
G	0.430 BSC		10.92	BSC
H	0.215 BSC		5.46	BSC
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89	BSC
N	0.760	0.830	19.31	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15	BSC
V	0.131	0.188	3.33	4.77

STYLE 1:

- PIN 1: BASE
 - EMITTER
- CASE: COLLECTOR

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